

# Switch mode Ultra-fast Power Rectifiers

Designed for use in switching power supplies, inverters and as free-wheeling diodes. These state-of-the-art devices have the following

## **Features**

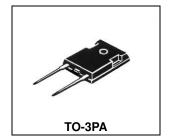
- \* High Surge Capacity
- \*Low Power Loss, High efficiency
- \* 150° C Operating Junction Temperature
- \*Low Stored Charge Majority Carrier Conduction
- \*Low Forward Voltage, High Current Capability
- \* High-Switching Speed 50 Nanosecond recovery Time
- \* Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O
- \* Pb free
- \* In compliance with EU RoHs directives

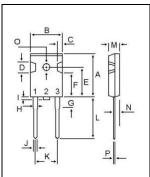




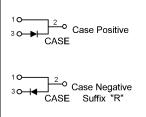
# ULTRA FAST RECTIFIERS

#### 30 AMPERES 400 VOLTS





DIM	MILLIMETERS					
	MIN	MAX				
Α	20.63	22.38				
В	15.38	16.20				
С	1.90	2.70				
D	5.10	6.10				
E	14.81	15.22				
F	11.72	12.84				
G	4.20	4.50				
Н	1.82	2.46				
- 1		1.25				
J	0.89	1.53				
K	10.52	11.32				
L	18.50	21.50				
М	4.68	5.36				
N	2.40	2.80				
0	3.25	3.65				
Р	0.55	0.70				



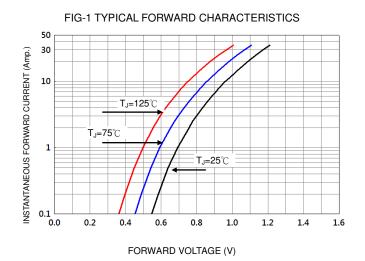
# **MAXIMUM RATINGS**

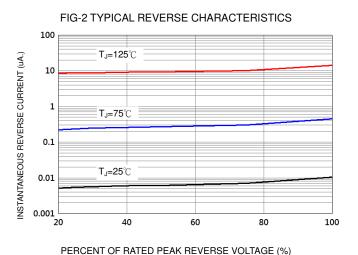
Characteristic	Symbol	UREA3040N	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	400	V
RMS Reverse Voltage	$V_{\text{R(RMS)}}$	280	V
Average Rectifier Forward Current	I <sub>F(AV)</sub>	30	Α
Peak Repetitive Forward Current (Rate V <sub>R</sub> , Square Wave, 20kHz)	I <sub>FM</sub>	30	Α
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-ware, single phase, 60Hz)	I <sub>FSM</sub>	450	А
Operating and Storage Junction Temperature Range	$T_{J}$ , $T_{stg}$	-65 to +150	$^{\circ}$ C

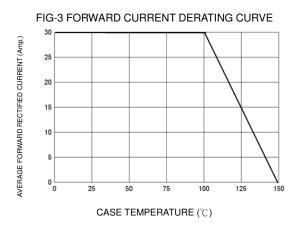
## **ELECTRICAL CHARACTERISTICS**

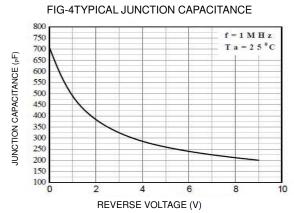
LELO II II OAL OI AITAO I LI II O II OO							
Characteristic	Symbol	Min.	Тур.	Max.	Unit		
Maximum Instantaneous Forward Voltage ( $I_F = 30 \text{ Amp } T_C = 25^{\circ}C$ ) ( $I_F = 30 \text{ Amp } T_C = 125^{\circ}C$ )	V <sub>F</sub>		1.17 0.97	1.50 	٧		
Maximum Instantaneous Reverse Current ( Rated DC Voltage, $T_C = 25^{\circ}C$ ) ( Rated DC Voltage, $T_C = 125^{\circ}C$ )	I <sub>R</sub>	 	0.01 20	15 	uA		
Reverse Recovery Time ( $I_F = 0.5 \text{ A}$ , $I_R = 1.0$ , $I_{rr} = 0.25 \text{ A}$ )	T <sub>rr</sub>		37	50	ns		
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	СР		280		₽F		

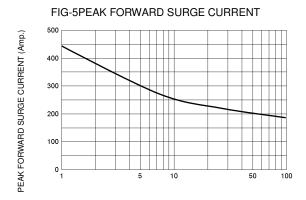


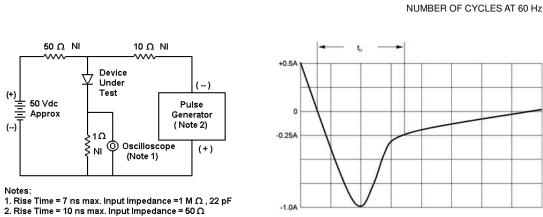












 $\label{eq:Settime} Set \ time \ base \ for \ 10/20 \ ns/cm \\ FIG-6 \ Reverse \ Recovery \ Time \ Characteristic \ and \ Test \ Circuit \ Diagram$ 



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